# NSN 5961-00-434-9256

Transistor - Page 1 of 1



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# **Inclosure Material:**

Metal

**Overall Length:** 

1.070 inches

Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

# **Overall Width Across Flats:**

0.437 inches

# Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

30.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Test Data Document:**

18876-10112519 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Thread Series Designator:

Unf

# Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

# Fiig:

A110a0